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## 10A, 100V - 200V Ultra Fast Surface Mount Rectifier

#### FEATURES

- AEC-Q101 qualified
- Planar technology
- Low power loss, high efficiency
- Ideal for automated placement
- Moisture sensitivity level: level 1, per J-STD-020
- RoHS Compliant
- Halogen-free

#### **APPLICATIONS**

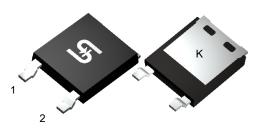
- High frequency switching
- DC/DC
- Snubber

#### **MECHANICAL DATA**

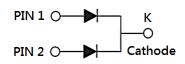
- Case: ThinDPAK
- Molding compound meets UL 94V-0 flammability rating
- Terminal: Matte tin plated leads, solderable per J-STD-002
- Meet JESD 201 class 2 whisker test
- Polarity: As marked
- Weight: 0.194g (approximately)

KEY PARAMETERS		
PARAMETER	VALUE	UNIT
lf	10	А
V <sub>RRM</sub>	100 - 200	V
IFSM	130	А
T <sub>J MAX</sub>	175	°C
Package	ThinDPAK	
Configuration	Common o	athode

## Po Roths HALOGEN ThmDPAK®



ThinDPAK



ABSOLUTE MAXIMUM RATINGS (T <sub>A</sub> = 25°C unless otherwise noted)					
PARAMETER		SYMBOL	PUAD10BCH	PUAD10DCH	UNIT
Marking code on the device			UAD10BC	UAD10DC	
Repetitive peak reverse voltage		Vrrm	100	200	V
Reverse voltage, total rms value		VR(RMS)	70	140	V
Forward current per device		l <sub>F</sub>	10		А
Surge peak forward current single half	t = 8.3ms		130 270		A
sine-wave superimposed on rated load per diode	t = 1.0ms	IFSM			
Junction temperature		TJ	-55 to +175		°C
Storage temperature		Tstg	-55 to +175		°C



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THERMAL PERFORMANCE				
PARAMETER	SYMBOL	ТҮР	UNIT	
Junction-to-lead thermal resistance	R <sub>ØJL</sub>	3.5	°C/W	
Junction-to-ambient thermal resistance	Reja	11.8	°C/W	
Junction-to-case thermal resistance	Rejc	2.0	°C/W	

Thermal Performance Note: Mounted on heat sink with 2" x 3" x 0.25" Al-Plate

	ATIONS (T <sub>A</sub> = 25°C unless otherwise				
PARAMETER	CONDITIONS	SYMBOL	ΤΥΡ	MAX	UNIT
Forward voltage per diode <sup>(1)</sup>	I⊧ = 2.5A, TJ = 25°C	VF	0.81	-	V
	I <sub>F</sub> = 2.5A, T <sub>J</sub> = 125°C		0.66	-	V
	$I_F = 5.0A, T_J = 25^{\circ}C$	VF	0.88	0.95	V
	I <sub>F</sub> = 5.0A, T <sub>J</sub> = 125°C		0.74	-	V
Reverse current @ rated V <sub>R</sub>	$T_J = 25^{\circ}C$	– I <sub>R</sub>	-	2	μA
per diode <sup>(2)</sup>	T <sub>J</sub> = 125°C		2	-	μA
Junction capacitance per diode	$1MHz, V_R = 4.0V$	CJ	74	-	pF
Povoroo rocovoru timo	$I_F = 0.5A, I_R = 1.0A, I_{rr} = 0.25A$	+	-	25	ns
Reverse recovery time	I <sub>F</sub> = 1.0A, di/dt = 50A/µs, V <sub>R</sub> = 30V	trr	24	-	
Reverse recovery current		I <sub>RM</sub>	2.9	-	А
Reverse recovery charge	I <sub>F</sub> = 5.0A, di/dt = 200A/µs, V <sub>R</sub> = 100V	Qrr	41	-	nC
Reverse recovery time		t <sub>rr</sub>	20	-	ns

Notes:

1. Pulse test with PW = 0.3ms

2. Pulse test with PW = 30ms

ORDERING INFORMATION		
ORDERING CODE <sup>(1)</sup>	PACKAGE	PACKING
PUAD10xCH	ThinDPAK	4,500 / Tape & Reel

Notes:

1. "x" defines voltage from 100V(PUAD10BCH) to 200V(PUAD10DCH)



### PUAD10BCH – PUAD10DCH

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#### **CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25°C unless otherwise noted)

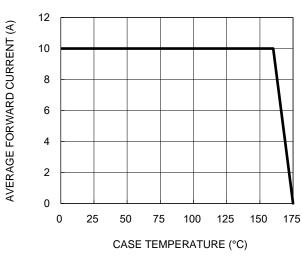
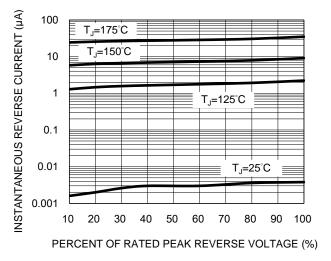
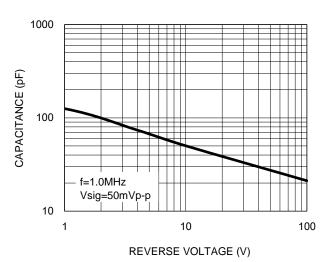


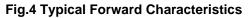
Fig.1 Forward Current Derating Curve

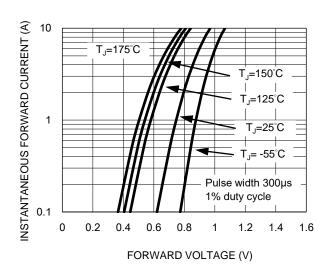
#### **Fig.3 Typical Reverse Characteristics**



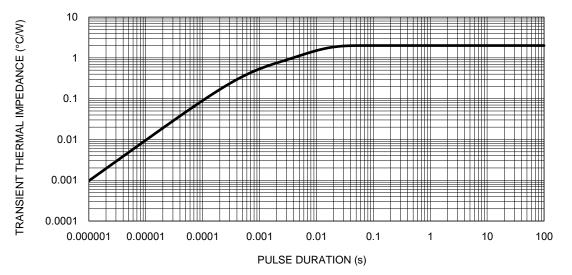


#### **Fig.2 Typical Junction Capacitance**





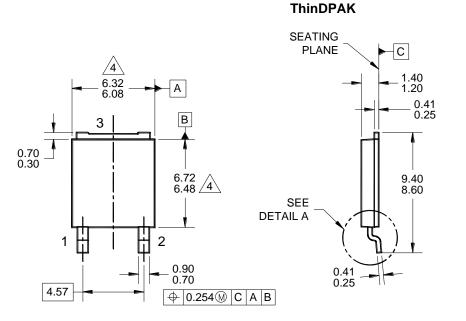


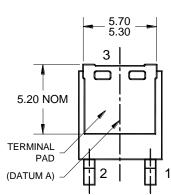


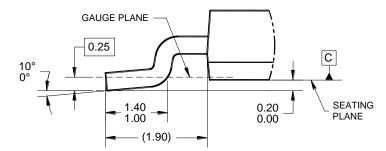


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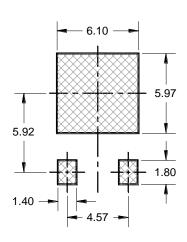
### PACKAGE OUTLINE DIMENSIONS



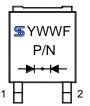




DETAIL A, ROTATED -90° (SCALE 4:1)



SUGGESTED PAD LAYOUT



#### MARKING DIAGRAM

YWW	= DATE CODE
F	= FACTORY CODE
P/N	= MARKING CODE

#### NOTES: UNLESS OTHERWISE SPECIFIED

- 1. ALL DIMENSIONS ARE IN MILLIMETERS.
- 2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
- 3. PACKAGE OUTLINE REFERENCE: JEDEC TO-252, VARIATION AE, ISSUE F.
- 4 MOLDED PLASTIC BODY DIMENSIONS DO NOT INCLUDE MOLD FLASH, PROTRUSION, OR GATE BURRS.
- 5. DWG NO. REF: HQ2SD07-TDPAK-065 REV A.



## PUAD10BCH – PUAD10DCH

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